NSN 5962-01-046-4800

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-046-4800 **Body Length:** Between 0.750 inches and 0.770 inches **Body Width:** Between 0.260 inches and 0.280 inches **Body Height:** Between 0.140 inches and 0.160 inches **Operating Tempurature Range:** +0.0/+75.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and hermetically sealed and positive outputs and programmable and programmed and bipolar and w/decoded output and expandable and wire-or outputs and 3-state output and w/buffered output and high speed and w/disable and w/enable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 97384-56602-40003 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

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Demilitarization: Yes - demil/mli